

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	12	(("5039655") or ("5956287") or ("6153443") or ("6165803") or ("6261893") or ("6429044")).PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/18 16:32
S2	0	10/612676	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/18 16:56
S3	1434	(257/295).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/18 17:01
S4	1476	(438/3).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/18 17:03
S5	3116	memory near3 wafer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/18 17:03
S6	7	S5 and magnet\$7 near3 permeable near3 shield	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/20 13:33
S7	7	S5 and magnet\$7 near3 permeable near3 shield	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/18 17:25
S8	14	S5 and magnet\$7 near3 shield	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/18 17:54
S9	5787395	"9" not S7	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/18 17:25

S10	7	S8 not S7	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/18 17:25
S11	38	S5 and ((magnetic adj random adj access adj memory) MRAM)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/18 17:53
S12	6	S11 and S8	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/18 17:41
S13	518	S5 and ((magnetic adj random adj access adj memory) RAM)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/20 11:53
S14	6	S13 and magnet\$7 near3 shield	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/18 17:54
S15	0	S14 not S12	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/18 17:54
S16	0	S5 and ((magnetic adj random adj access adj memory) RAM) and shield\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/18 17:55
S17	89	S5 and ((magnetic adj random adj access adj memory) RAM) and shield\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/20 08:21
S18	53921	"5" and ((magnetic adj random adj access adj memory) RAM) and shield\$3 and bit daj line and word adj line	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/20 08:21
S19	64697	"5" and ((magnetic adj random adj access adj memory) RAM) and shield\$3 and bit daj line and word adj line	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/20 08:22

S20	3117	memory near3 wafer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/20 08:22
S21	59646	S20 and ((magnetic adj random adj access adj memory) RAM) and shield\$3 and bit daj line and word adj line	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/20 08:23
S22	89	S20 and ((magnetic adj random adj access adj memory) RAM) and shield\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/20 11:37
S23	59646	S22 and bit daj line and word adj line	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/20 08:23
S24	22	S22 and bit adj line and word adj line	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/20 08:33
S25	1434	(257/295).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/20 08:27
S26	14	S25 and S20	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/20 08:25
S27	69	S25 and shield\$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/20 08:28
S28	25	S25 and shield\$4 near3 layer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/20 08:28
S29	12	S28 and bit adj line and word adj line	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/20 08:33

S30	8	"L5" and ((magnetic adj random adj access adj memory) MRAM) and shield\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/20 11:37
S31	5176	((magnetic adj random adj access adj memory) MRAM)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/20 11:54
S32	2739	S31 and array	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/20 11:54
S33	2898	S31 and array	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/20 11:54
S34	31	S33 and memory near3 wafer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/21 10:19
S35	5	S34 and (shied\$3 cap)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/20 12:12
S37	3	S33 and shied\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/20 12:40
S39	15	S33 and alumina and permalloy near3 "nife"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/20 13:32
S40	2739	S31 and S32	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/20 13:32
S41	4	S40 and magnet\$7 near3 permeable near3 shield	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/20 14:09

S42	3117	memory near3 wafer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/20 14:09
S43	7	S42 and magnet\$7 near3 permeable near3 shield	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/20 14:26
S44	13	S42 and magnet\$7 near3 shield	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/20 14:28
S45	16	S42 and magnet\$7 near3 (shield protect\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/20 14:28
S46	17	S42 and magnet\$7 near3 (shield protect\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/20 14:43
S47	6	S42 and magnet\$7 near3 (shield protect\$3) and MRAM	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/20 14:53
S48	11	S46 not S47	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/20 15:32
S49	4	(("5650958") or ("5729410")).PN	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/20 15:33
S50	5184	((magnetic adj random adj access adj memory) MRAM)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/21 13:12
S51	2905	S50 and array	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/21 10:19

S52	0	S51 and memory near3 wafer and array and bon\$3 near3 pad	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/21 10:21
S53	13	S51 and bon\$3 near3 pad	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/21 13:11
S54	242	"L2" and bon\$3 near3 pad and packag\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/21 13:14
S55	0	S54 and ((magnetic adj random adj access adj memory) MRAM)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/21 13:12
S56	5184	((magnetic adj random adj access adj memory) MRAM)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/21 13:14
S57	11	S56 and bon\$3 near3 pad and packag\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/21 13:14